## Time reversal invariant 2d lattice models

Student seminar on topoligical insulators

University of Konstanz

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December 15, 2016

- 2 The Kane and Mele model
- Bernevig-Hughes-Zhang-model
- Properties of edge states
- 5 The  $\mathbb{Z}_2$ -invariant
- 6 Absence of backscattering
- Experimental realisation

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$$\begin{aligned} \mathcal{T}_1 &= i s_y \mathcal{K} & \text{with} & \mathcal{T}_1^2 &= -\mathbb{1} \\ \mathcal{T}_2 &= s_x \mathcal{K} & \text{with} & \mathcal{T}_2^2 &= \mathbb{1} \end{aligned}$$

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• C acts on internal degree of freedom (DOF) (e.g. sublattice, spin,...)

## Graphene

- 2d honeycomb lattice
- Sublattice degree of freedom
- Dirac cones in the band structure
- Valley degree of freedom:

$$\begin{split} \mathbf{K} &= \frac{2\pi}{3a} \left( 1, \frac{1}{\sqrt{3}} \right) \\ \mathbf{K}' &= \frac{2\pi}{3a} \left( 1, -\frac{1}{\sqrt{3}} \right) \end{split}$$

No band gap

Graphics taken from A. H. Castro Neto, F. Guinea, N. M. R Peres, K. S. Novoselov, A. K. Geim: The electronic properties of graphene. In: Arxiv preprint. 2007, arxiv:0709.1163v2





Idea: doubling the Haldande-model by introducing spin

Start from low energy Hamitonian near the Dirac cones at K and K' ( $\phi = 0$ )

$$H_0 = -i\hbar v_F \Psi^\dagger \left(\sigma_x au_z \partial_x + \sigma_y \partial_y
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Introduce TRI spin-orbit-coupling  $H_{SO} = \lambda_{SO} \Psi^{\dagger} \sigma_z \tau_z s_z \Psi$ 

Doubly degenerate bands with a gap:  $E_k = \pm \sqrt{(\hbar v_F k)^2 + \lambda_{
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Tight binding model: two identical copies of the Haldane model C. L. Kane, E. J. Mele. Phys. Rev. Lett., 95, 226801 (2005)

$$H = t_1 \sum_{\langle i,j \rangle,\sigma} c^{\dagger}_{i\sigma} c_{i\sigma} + i\lambda_{SO} \sum_{\langle \langle i,j \rangle \rangle,\sigma,\sigma'} \nu_{ij} c^{\dagger}_{i\sigma} s^{z}_{\sigma\sigma'} c_{j\sigma'}$$

$$\begin{split} h_{\uparrow}(\mathbf{K} + \mathbf{k}) &= \sigma_{x}k_{x} + \sigma_{y}k_{y} + \lambda_{\mathsf{SO}}\sigma_{z}s_{z} \quad h_{\uparrow}(\mathbf{K}' + \mathbf{k}) = -\sigma_{x}k_{x} + \sigma_{y}k_{y} - \lambda_{\mathsf{SO}}\sigma_{z}s_{z} \\ h_{\downarrow}(\mathbf{K} + \mathbf{k}) &= \sigma_{x}k_{x} + \sigma_{y}k_{y} - \lambda_{\mathsf{SO}}\sigma_{z}s_{z} \quad h_{\downarrow}(\mathbf{K}' + \mathbf{k}) = -\sigma_{x}k_{x} + \sigma_{y}k_{y} + \lambda_{\mathsf{SO}}\sigma_{z}s_{z} \end{split}$$

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 $h_{\uparrow(\downarrow)}$  known from Haldane model  $\Rightarrow$  Hall conductance  $\pm 1$  for  $\uparrow(\downarrow) =$  quantum spin Hall effect



Apply construction rule on QWZ-model  $\Rightarrow$  Bernevig-Hughes-Zhang-model

$$H_{\text{BHZ}}(\mathbf{k}) = s_0 \otimes \left[ \left( u + \cos k_x + \cos k_y \right) \sigma_z + \sin k_x \sigma_x \right] + s_z \otimes \sin k_y \sigma_y + s_x \otimes C$$

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- Introduce Hermitian coupling  $C = C^{\dagger}$

## Properties of edge states

#### $\mathbf{C} = \mathbf{0}$

Direct sum of two Chern insulators with opposite QKramers's pair of edge state branches on each edge Edge states propagate in opposite directions Edge state branches linked by both  $\mathcal{T}_1 \And \mathcal{T}_2$ TRI 1d Brillouin zone  $-\pi \le k_x \le \pi$  has to be symmetric  $\Rightarrow N_+ = N_- \Leftrightarrow Q = N_+ - N_- = 0 = \text{const}$ 



Parameter u = 1.2

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#### $\mathbf{C} = \mathbf{C}^\mathsf{T}$

Example with  $C = 0.3\sigma_x$ 

Respects  $\mathcal{T}^2=1$  symmetry

Can gap edge state branches out

Hopping between counterpropagating edge states



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#### $\mathbf{C} = -\mathbf{C}^\mathsf{T}$

Example with  $C = 0.3\sigma_y$ Respects  $T^2 = -1$  symmetry Crossing is protected



Q = 0 & symmetry of the BZ  $\Rightarrow$  creation/annihilation of egde states in pairs of Kramer's pairs

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Crossings at  $k_x = 0, \pm \pi$  (TRIM) are protected by Kramer's degeneracy

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Not well defined on sets of zero measure:



Consider a 2d lattice with internal degree of freedom Finite extent in y-direction and periodic boundaries in x rectangular unit cells  $N_x \times N_y$  and translational invariance along x

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> States from Bloch theorem: left / right propagating  $(\pm)$  usual momentum eigenstates: transverse mode, inernal DOF: with group velocity:

$$\begin{split} |l, \pm\rangle &= |k_{l,\pm}\rangle \otimes |\phi_{l,\pm}\rangle \\ \text{with mode } l \in \{1, ..., N\} \\ |k_{l,\pm}\rangle &= \frac{1}{\sqrt{N_x}} \sum_{m_x=1}^{N_x} e^{ikm_x} |m_x\rangle \\ |\phi_{l,\pm}\rangle \\ v_{l,\pm} &= \frac{\partial E(k)}{\partial k} \Big|_{k=k_{l,\pm}} \end{split}$$

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Re-normalize: different states carry same particle current trough arbitrary cross section

$$|l,\pm
angle_c=rac{1}{\sqrt{|m{v}_{l,\pm}|}}\,|l,\pm
angle$$



Consider scattering at disordered region (gray) with respect to coefficients:

$$\mathbf{a}^{\text{in}} = \left(a_{L,1}^{\text{in}}, ... a_{L,N}^{\text{in}}, a_{R,1}^{\text{in}}, ..., a_{R,N}^{\text{in}}\right) \mapsto \mathbf{a}^{\text{out}} = \left(a_{L,1}^{\text{out}}, ... a_{L,N}^{\text{out}}, a_{R,1}^{\text{out}}, ..., a_{R,N}^{\text{out}}\right)$$



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Energy eigenstate outside scattering region:

$$|\psi\rangle = \sum_{l=1}^{N} a_{L,l}^{\text{in}} |l, +, L\rangle_{c} + a_{R,l}^{\text{in}} |l, -, R\rangle_{c} + a_{L,l}^{\text{out}} |l, -, L\rangle_{c} + a_{R,l}^{\text{out}} |l, +, R\rangle_{c}$$



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Unitary  $2N \times 2N$  scattering matrix S:  $\mathbf{a}^{\text{out}} = S \mathbf{a}^{\text{in}} = \begin{pmatrix} r & t' \\ t & r' \end{pmatrix} \mathbf{a}^{\text{in}}$ 



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Eigenvalues of  $tt^{\dagger}$ ,  $t't'^{\dagger}$ ,  $1 - rr^{\dagger}$  and  $1 - r'r'^{\dagger}$  are the same (transmission eigenvalues)

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$$\begin{aligned} -\mathcal{T}|\psi\rangle &= \sum_{l=1}^{N} -a_{L,l}^{\mathsf{in}^*} |l, -, L\rangle_c - a_{R,l}^{\mathsf{in}^*} |l, +, R\rangle_c + \left(S^* a^{\mathsf{in}^*}\right)_{L,l} |l, +, L\rangle_c + \left(S^* a^{\mathsf{in}^*}\right)_{R,l} |l, -, R\rangle_c \\ &= \sum_{l=1}^{N} \left(S^* a^{\mathsf{in}^*}\right)_{L,l} |l, +, L\rangle_c + \left(S^* a^{\mathsf{in}^*}\right)_{R,l} |l, -, R\rangle_c \\ &+ \left(-S^T S^* a^{\mathsf{in}^*}\right)_{L,l} |l, -, L\rangle_c + \left(-S^T S^* a^{\mathsf{in}^*}\right)_{R,l} |l, +, R\rangle_c \end{aligned}$$

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 ${\cal S}$  is uniquely at any energy  $\Rightarrow {\cal S} = - {\cal S}^{{\cal T}}$ 

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For D = 1 at least one transmission eigenvalue is 1, i.e. there is at least one linear combination of incoming edge states from both sides that is perfectly transmitted through a time-reversal symmetryc defect.

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For D = 1 at least one transmission eigenvalue is 1, i.e. there is at least one linear combination of incoming edge states from both sides that is perfectly transmitted through a time-reversal symmetryc defect.



No backscattering at small constriction

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$$S = egin{pmatrix} r & t' \\ t & r' \end{pmatrix}$$
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Zero transmission = backscattering

## Absence of backscattering: robustness against disorder

Finite disordered TRI 2d topological insulator with arbitrary geometry and TRS disorder

Inside the box switch disorder off and straighten geometry out

Apply adiabatic deformation in the box make such that there is only one Kramer's pair of edge states

Disordered region is time reversal symmetric scatterer



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 $\Rightarrow$  Any segment of the edge supports at least one perfectly transmitted Kramer's pair of edge states

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In HgTe these bands are inverted.

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П	73	20.0  imes 13.3
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Breaking time reversal symmetry? Sample like II

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